

Features

- Hermetic 6-pin TO-5 package
- 1500Vdc isolation voltage
- High Speed 1MHz
- Small package outline
- High reliability and rugged construction
- High reliability screening available
- Radiation tolerant
- Open collector output
- Operating temperature range -55°C to +125°C

Description

The IBH300 consists of a phototransistor optically coupled to an AlGaAs infrared-emitting diode in a hermetic TO-5 package.

Schematic Diagram

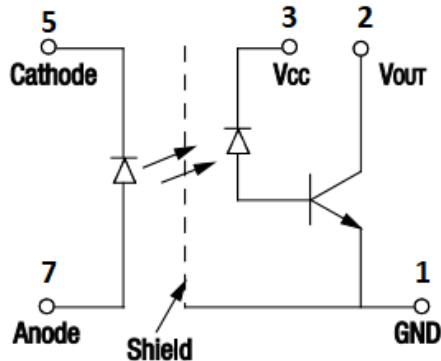


Figure 1. IBH300 Schematic Diagram

Applications

- Switch mode power supplies
- Computer peripheral interface
- Motor control
- Ground signal isolation

Package Dimensions in inches (mm)

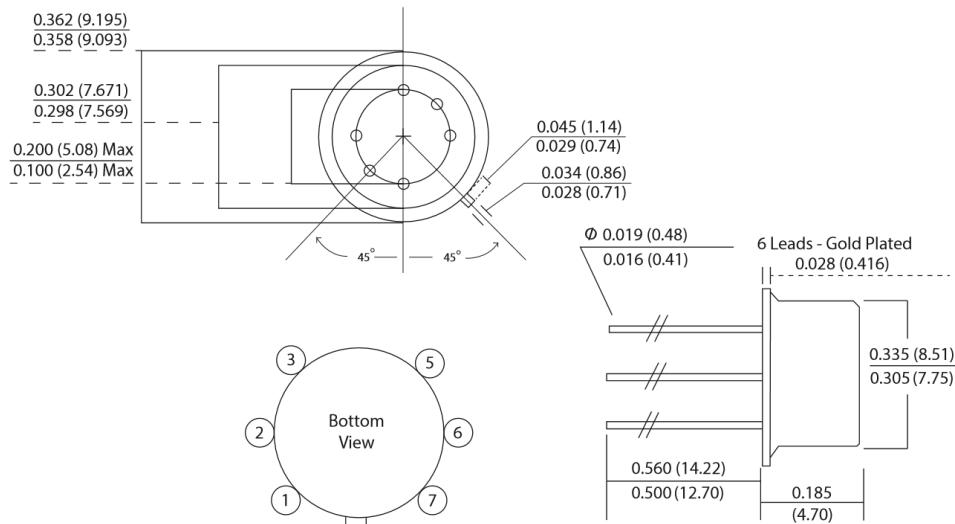


Figure 2. IBH300 Package Dimensions

Absolute Maximum Rating at 25°C (Note 1)

Symbol	Parameters	Ratings	Units	Notes
V _{DC}	Isolation voltage	-1500 to +1500	V	2
T _{OPR}	Operating temperature	-55 to +125	°C	
T _{TSG}	Storage temperature	-65 to +150	°C	
T _{SOL}	Soldering temperature (10 seconds maximum)	240	°C	
Emitter				
P _D	Emitter power dissipation	36	mW	
I _F	Forward current	20	mA	
I _{F(TRANS)}	Peak transient current (≤1ms P.W.)	40	mA	
V _R	Reverse voltage	5	V	
Detector				
P _D	Detector power dissipation	50	mW	3
I _O	Output Current	8	mA	
I _{O(Peak)}	Peak Output Current	16	mA	
V _{CC}	Supply Voltage	-0.5 to +18.0	V	
V _O	Output Voltage	-0.5 to +18.0	V	

Notes

1. When using this product, please observe the absolute maximum ratings. Only one parameter may be set at the limit to ensure no damage to the device. Exceeding any of the limits listed here may damage the device.
2. Measured between input pins 1 and 6 shorted together, and output pins 2, 3, 4, and 5 shorted together. T_A = 25°C and duration = 1sec.
3. Linear derating factor: 1.4 mW/°C above 100°C

ESD Precaution

Please be advised that normal static precautions should be taken in the handling and assembly of this device to prevent damage or degradation which may be induced by electrostatic discharge (ESD).

Electrical Characteristics

$T_A = -55^\circ\text{C}$ to $+125^\circ\text{C}$ (unless otherwise specified) (Note 1)

Emitter Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V_F	Forward Voltage	$I_F=10\text{mA}$	-	1.8	2.5	V	
B_{VR}	Input Breakdown Reverse Voltage	$I_R=10\mu\text{A}$	3	-	-	V	

Detector Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
V_{OL}	Logic Low Output Voltage	$I_F=10\text{mA}, I_{OL}=1.5\text{mA}, V_{CC}=4.5\text{V}$	-	0.15	0.4	V	
I_{OH}	Logic High Output Current	$I_F=0\text{mA}, V_{CC}=15\text{V}, V_O=15\text{V}$	-	0.05	100.0	μA	
I_{CCL}	Logic Low Supply Current	$I_F=10\text{mA}, V_{CC}=15\text{V}, V_O=\text{open}$	-	40	200	μA	
I_{CCH}	Logic High Supply Current	$I_F=0\text{mA}, V_{CC}=15\text{V}, V_O=\text{open}$	-	0.05	10	μA	

Transfer Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
CTR	Current Transfer Ratio	$I_F=10\text{mA}, V_{CC}=4.5\text{V}, V_O=0.4\text{V}$	15	25	-	%	2
I_{IO}	Input to Output Leakage Current	$V_{IO}=1500\text{VDC}$ Relative Humidity $\leq 50\%$ $T_A=25^\circ\text{C}$	-	-	1	μA	3

Propagation Delay Time

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
t_{PHL}	Logic High to Low	$I_F=10\text{mA}, V_{CC}=5\text{V},$ $R_L=4.1\text{k}\Omega, T_A=25^\circ\text{C}$	-	0.3	1.0	μs	4
t_{PLH}	Logic Low to High		-	0.5	2.0		4

Notes

1. Performance guaranteed only under conditions listed in above tables.
2. CTR is the ratio of the output collector current I_{C_ON} to the forward LED current I_F multiplied by 100%
3. Measured between input pins 1 and 6 shorted together, and output pins 2, 3, 4, and 5 shorted together. $T_A = 25^\circ\text{C}$ and duration = 1sec.
4. A ceramic bypass capacitor (0.01 μF to 0.1 μF) between pins 3 and 5 is required to stabilize the operation of the amplifier.

Typical Characteristic Curves

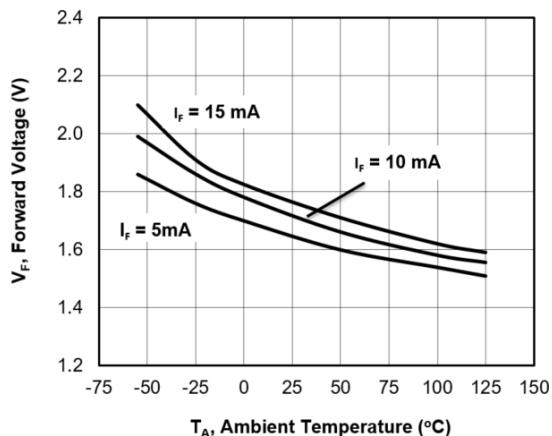


Figure 3. Forward Voltage vs Temperature

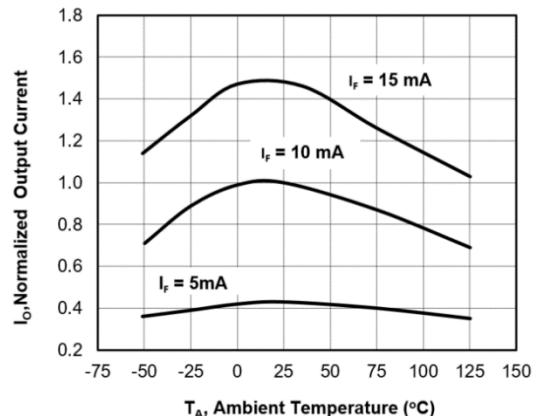


Figure 4. Output Current vs Temperature

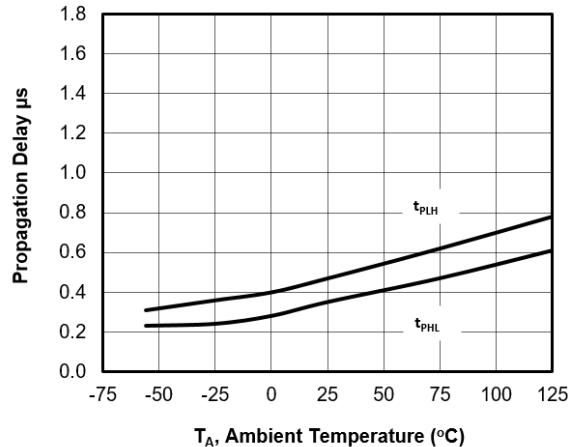


Figure 5. Propagation Delay vs Temperature

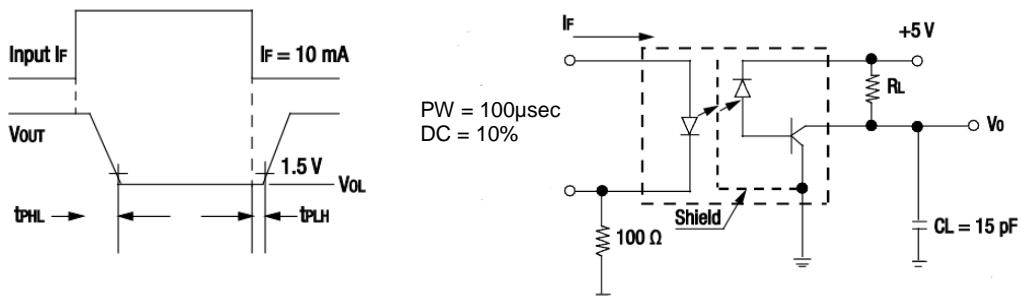


Figure 6. IBH300 Switching Test Circuit



Radiation Tolerant High-Speed 1MHz Hermetic Optocoupler **IBH300**

Ordering Information

Manufacturing Part Number	Part Description
IBH300	Radiation Tolerant High-Speed 1MHz Hermetic 6-pin TO-5 Package

Revision History

Date	Revision Description
January 2017	Initial Release
January 2021	Pinout revision – v1

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